

# isc Silicon NPN Power Transistor

## 2SC3307

### DESCRIPTION

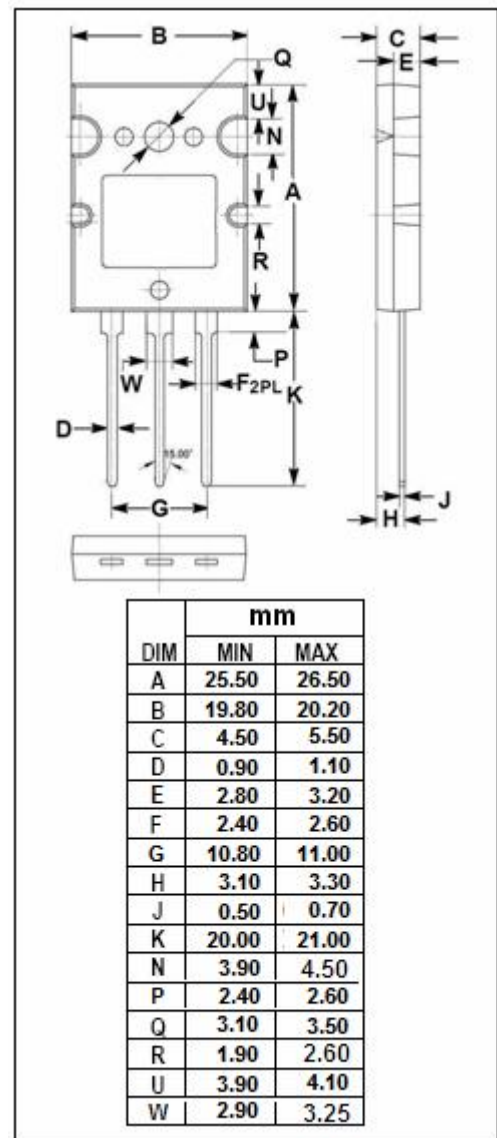
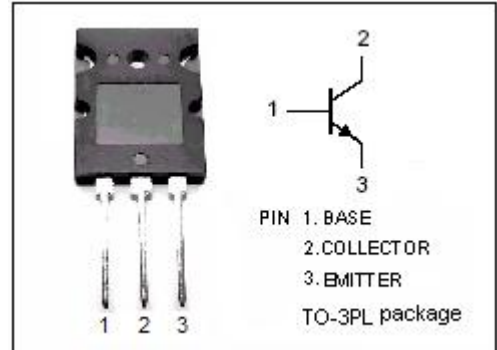
- High Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 800V(\text{Min})$
- High Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

- High speed and high voltage switching applications.
- Switching regulator applications.
- High speed DC-DC converter applications.

### ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	900	V
$V_{CEO}$	Collector-Emitter Voltage	800	V
$V_{EBO}$	Emitter-Base Voltage	7	V
$I_C$	Collector Current-Continuous	10	A
$I_{CM}$	Collector Current-Pulse	15	A
$I_B$	Base Current-Continuous	3	A
$P_C$	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	150	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$



**isc Silicon NPN Power Transistor****2SC3307****ELECTRICAL CHARACTERISTICS** $T_C=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 10\text{mA}$ ; $I_B = 0$	800			V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 1\text{mA}$ ; $I_E = 0$	900			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 5\text{A}$ ; $I_B = 1\text{A}$			1.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 5\text{A}$ ; $I_B = 1\text{A}$			1.5	V
$I_{CBO}$	Collector Cutoff Current	$V_{CB} = 800\text{V}$ ; $I_E = 0$			100	$\mu\text{A}$
$I_{EBO}$	Emitter Cutoff Current	$V_{EB} = 7\text{V}$ ; $I_C = 0$			1	mA
$h_{FE-1}$	DC Current Gain	$I_C = 10\text{mA}$ ; $V_{CE} = 5\text{V}$	10			
$h_{FE-2}$	DC Current Gain	$I_C = 5\text{A}$ ; $V_{CE} = 5\text{V}$	10			
Switching times						
$t_r$	Rise Time	$I_C = 1\text{A}$ , $I_{B1} = -I_{B2} = 0.4\text{A}$ $R_L = 400\Omega$ ; $V_{CC} \approx 400\text{V}$ $P_W = 20\mu\text{s}$ ; Duty Cycle $\leq 1\%$			1.0	$\mu\text{s}$
$t_{stg}$	Storage Time				3.0	$\mu\text{s}$
$t_f$	Fall Time				1.0	$\mu\text{s}$

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